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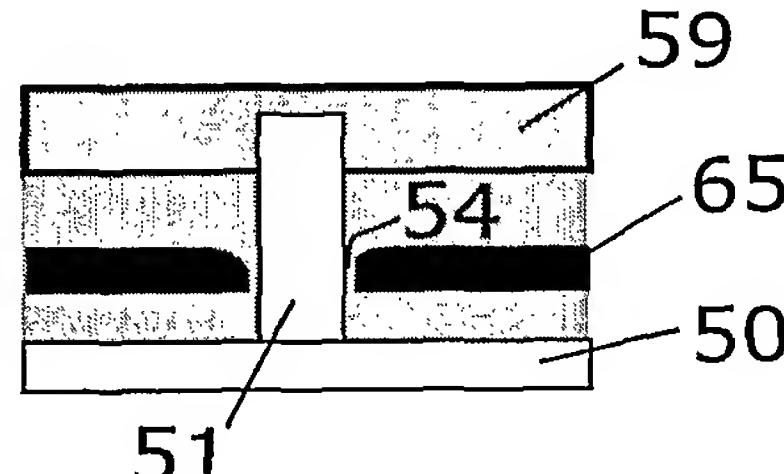
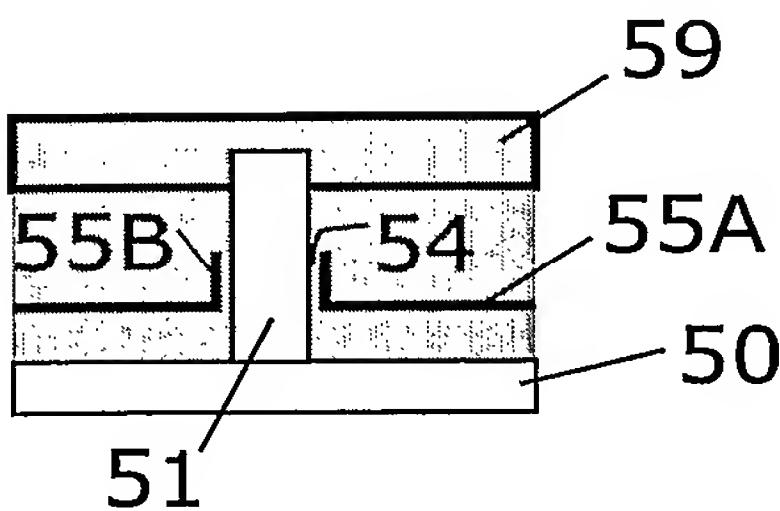
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- (71) Applicant (*for all designated States except US*): **KONINKLIJKE PHILIPS ELECTRONICS N.V. [NL/NL]; Groenewoudseweg 1, NL-5621 BA Eindhoven (NL).**
- (72) Inventors; and
- (75) Inventors/Applicants (*for US only*): **BAKKERS, Erik, P., A., M. [NL/NL]; Prof. Holstlaan 6, NL-5656 AA Eindhoven (NL). WOLTERS, Robertus, A., M. [NL/NL]; Prof. Holstlaan 6, NL-5656 AA Eindhoven (NL). KLOOTWIJK, Johan, H. [NL/NL]; Prof. Holstlaan 6, NL-5656 AA Eindhoven (NL).**
- (74) Agents: **ELEVLD, Koop, J. et al.; Prof. Holstlaan 6, NL-5656 AA Eindhoven (NL).**
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(54) Title: SEMICONDUCTOR DEVICE COMPRISING A HETEROJUNCTION



(57) **Abstract:** A semiconductor device with a heterojunction. The device comprises a substrate and at least one nanostructure. The substrate and nanostructure is of different materials. The substrate may e.g. be of a group IV semiconductor material, whereas the nanostructure may be of a group III-V semiconductor material. The nanostructure is supported by and in epitaxial relationship with the substrate. A nanostructure may be the functional component of an electronic device such as a gate-around-transistor device. In an embodiment of a gate-around-transistor, a nanowire (51) is supported by a substrate (50), the substrate being the drain, the nanowire the current channel and a top metal contact (59) the source. A thin gate dielectric (54) is separating the nanowire and the gate electrode (55A, 55B).

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